

BUV27G Information



For Reference Only

Part Number BUV27G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 120V 12A TO-220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BUV27G Specifications

Manufacturer Part Number	BUV27G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-220-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	12A
Voltage - Collector Emitter Breakdown (Max)	120V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 800mA, 8A
Current - Collector Cutoff (Max)	-
DC Current Gain (hFE) (Min) @ Ic, Vce	-
Power - Max	70W
Frequency - Transition	-
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3
Supplier Device Package	TO-220AB
	Report errors?

BUV27G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BUV27G Payment Methods









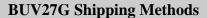
























If you have any question about BUV27G, please do not hesitate to contact us!

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